



Docket No.: 071971-0388

PATENT

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re Application of	:	Customer Number: 20277
	:	
Masao UCHIDA et al.	:	Confirmation Number: 6077
	:	
Application No.: 10/553,628	:	Group Art Unit: 2814
	:	
Filed: October 19, 2005	:	Examiner: Mursalin B. HAFIZ
For: A HIGH-BREAKDOWN-VOLTAGE INSULATED GATE SEMICONDUCTOR DEVICE		

PRELIMINARY AMENDMENT

Mail Stop NEW APPLICATION
Commissioner for Patents
P.O. Box 1450
Alexandria, VA 22313-1450

Sir:

✓ Prior to examination of the above-referenced application, please amend the application as follows:

Amendments to the Title begin on page 2 of this paper.

Remarks/Arguments begin on page 3 of this paper.

IN THE TITLE:

Please change the title of the invention to read as follows:

--A HIGH-BREAKDOWN-VOLTAGE INSULATED GATE SEMICONDUCTOR
DEVICE--.